

RE46C311/2

Low-Input Leakage, Rail-to-Rail Input/Output Op Amps

Features

- Low Quiescent Current: 600 nA/Amplifier (typical)
- · Rail-to-Rail Input/Output
- Gain Bandwidth Product: 10 kHz (typical)
- Wide Supply Voltage Range: 1.8V to 5.5V
- · Unity Gain Stable
- · Available in Single and Dual Configurations
- Temperature Ranges: -10°C to +60°C

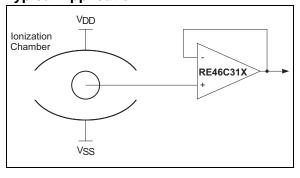
Applications

- · Ionization Smoke Detectors
- · Low Leakage High-Impedance Input Circuits
- · Battery-Powered Circuits

Design Aids

- MAPS (Microchip Advanced Part Selector)
- · Analog Demonstration and Evaluation Boards
- Application Notes

Typical Application



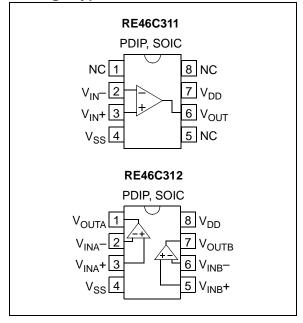
Description

The RE46C311/2 family of operational amplifiers (op amps) from Microchip Technology Inc. operate with a single-supply voltage as low as 1.8V, while drawing less than 1 μA (maximum) of quiescent current per amplifier. These devices are also designed to support rail-to-rail input and output operation. This combination of features supports battery-powered and portable applications.

The RE46C311/2 amplifiers have a gain-bandwidth product of 10 kHz (typical) and are unity gain stable. These specifications make these op amps appropriate for low-frequency applications, such as ionization smoke detectors and sensor conditioning.

The RE46C311/2 family operational amplifiers are offered in single (RE46C311), and dual (RE46C312) configurations.

Package Types



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DD} – V _{SS}	6.0V
Current at Input Pins	±2 mA
All Inputs and OutputsVSS	$_{\rm S}$ – 0.3V to V _{DD} + 0.3V
Difference Input voltage	V _{DD} - V _{SS}
Output Short Circuit Current	continuous
Current at Output and Supply Pins	±30 mA
Storage Temperature	65°C to +150°C
Junction Temperature	+150°C
ESD protection on all pins (HBM; MM).	≥ 4 kV; 400V

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

†† See Section 4.1, Rail-to-Rail Input.

DC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, T_A = +25°C, V_{CM} = $V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, V_L = $V_{DD}/2$, and V_L = 1 MΩ to V_L (refer to Figure 1-1 and Figure 1-2).							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Input Offset		<u> </u>	<u> </u>				
Input Offset Voltage	Vos	-3	_	+3	mV		
Drift with Temperature	$\Delta V_{OS}/\Delta T_{A}$	_	±2	_	μV/°C	T_A = -10°C to +60°C	
Power Supply Rejection	PSRR	70	76	_	dB	$V_{CM} = V_{SS}$	
Input Leakage Current and I	mpedance						
Input Leakage Current	I _{L1}	-0.75		0.75	pA	Non Inverting Input only, $V_{IN} = V_{DD}$ or V_{SS}	
		_	3.5	6		$T_A = +60^{\circ}C$	
Input Leakage Current	I _{L2}	-100	_	100	nA	Inverting input only	
Common Mode Input Impedance	Z _{CM}	_	10 ¹³ 6	_	Ω pF		
Differential Input Impedance	Z _{DIFF}	_	10 ¹³ 6	_	Ω pF		
Common Mode							
Common-Mode Input Range	V_{CMR}	V _{SS}	_	V_{DD}	V		
Common-Mode Rejection Ratio	CMRR	62	86	_	dB	$V_{DD} = 5V, V_{CM} = 0V \text{ to } 5.0V$	
Open-Loop Gain							
DC Open-Loop Gain (large signal)	A _{OL}	85	115	_	dB	$R_L = 50 \text{ k}\Omega \text{ to V}_L,$ $V_{OUT} = 0.1 \text{V to V}_{DD}\text{-}0.1 \text{V}$	
Output							
Maximum Output Voltage Swing	V _{OL} , V _{OH}	V _{SS} + 10	_	V _{DD} - 10	mV	$R_L = 50 \text{ k}\Omega \text{ to V}_L,$ 0.5V input overdrive	
Output Short Circuit Current	I _{SC}	_	5	_	mA	V _{DD} = 1.8V	
			27	-	mA	V _{DD} = 5.5V	
Power Supply							
Supply Voltage	V_{DD}	1.8	_	5.5	V		
Quiescent Current per Amplifier	IQ	0.3	0.6	1.0	μA	I _O = 0	

AC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Un $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, V_{L}						
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
AC Response						
Gain Bandwidth Product	GBWP	_	10	<u> </u>	kHz	
Slew Rate	SR	_	3.0	_	V/ms	
Phase Margin	PM	_	65	_	0	G = +1 V/V
Noise						
Input Voltage Noise	E _{ni}	_	5.0	_	μV _{P-P}	f = 0.1 Hz to 10 Hz
Input Voltage Noise Density	e _{ni}	_	170	_	nV/√Hz	f = 1 kHz
Input Current Noise Density	İni	_	0.6	_	fA/√Hz	f = 1 kHz

TEMPERATURE CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, $V_{DD} = +1.8V$ to $+5.5V$, $V_{SS} = GND$.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Temperature Ranges							
Operating Temperature Range	T _A	-10	_	+60	°C		
Storage Temperature Range	T _A	-65	_	+150	°C		
Thermal Package Resistances							
Thermal Resistance, 8L-PDIP	θ_{JA}	_	89.3	_	°C/W		
Thermal Resistance, 8L-SOIC	θ_{JA}	_	149.5	_	°C/W		

1.1 Test Circuits

The test circuits used for the DC and AC tests are shown in Figure 1-1 and Figure 1-2. The bypass capacitors are laid out according to the rules discussed in **Section 4.5**, **Supply Bypass**.

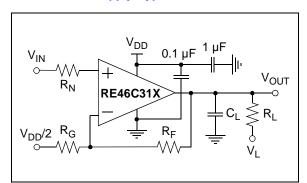


FIGURE 1-1: AC and DC Test Circuit for Most Non-Inverting Gain Conditions.

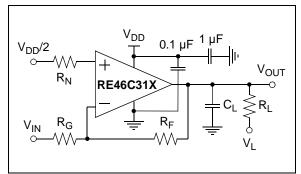


FIGURE 1-2: AC and DC Test Circuit for Most Inverting Gain Conditions.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +1.8V$ to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1$ M Ω to V_L , and $C_L = 60$ pF.

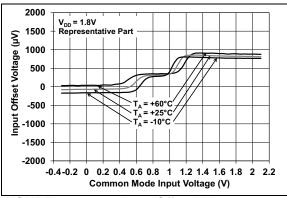


FIGURE 2-1: Input Offset Voltage vs. Common Mode Input Voltage with $V_{DD} = 1.8V$.

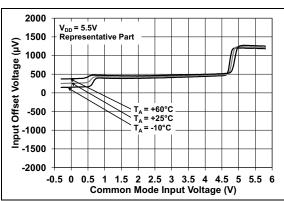


FIGURE 2-2: Input Offset Voltage vs. Common Mode Input Voltage with $V_{DD} = 5.5V$.

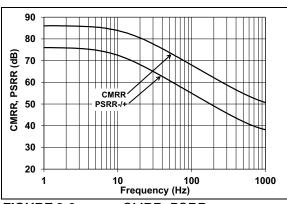


FIGURE 2-3: CMRR, PSRR vs. Frequency.

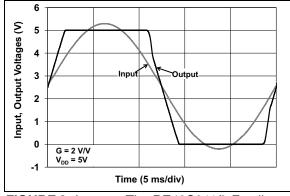


FIGURE 2-4: The RE46C311/2 Family Shows No Phase Reversal.

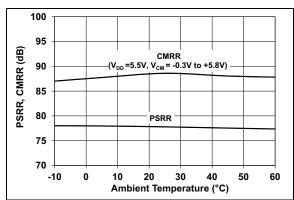


FIGURE 2-5: CMRR, PSRR vs. Ambient Temperature.

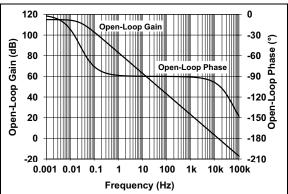


FIGURE 2-6: Open-Loop Gain, Phase vs. Frequency.

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 1 M Ω to V_L , and C_L = 60 pF.

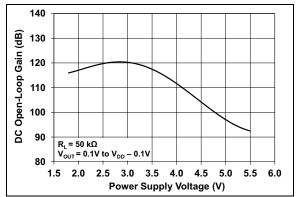


FIGURE 2-7: DC Open-Loop Gain vs. Power Supply Voltage.

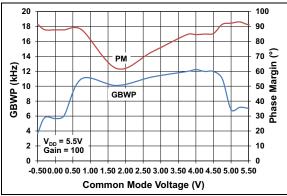


FIGURE 2-8: Gain Bandwidth Product, Phase Margin vs. Common Mode Input Voltage.

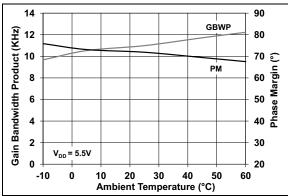


FIGURE 2-9: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature with $V_{DD} = 5.5V$.

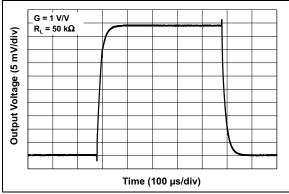


FIGURE 2-10: Small Signal Non-inverting Pulse Response.

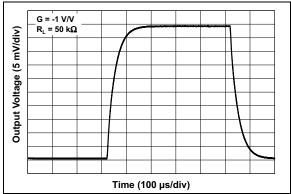


FIGURE 2-11: Small Signal Inverting Pulse Response.

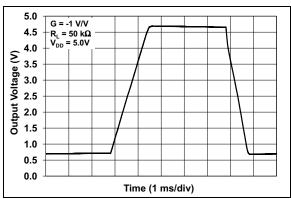


FIGURE 2-12: Large Signal Non-inverting Pulse Response.

RE46C311/2

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} \approx V_{DD}/2, V_L = V_{DD}/2, R_L = 1 M Ω to V_L, and C_L = 60 pF.

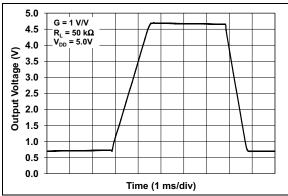


FIGURE 2-13: Large Signal Inverting Pulse Response.

3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

RE46C311	RE46C312	Symbol	Description
PDIP, SOIC	PDIP, SOIC,	Symbol	Description
6	1	V _{OUT} , V _{OUTA}	Analog Output (op amp A)
2	2	V _{IN} -, V _{INA} -	Inverting Input (op amp A)
3	3	V _{IN} +, V _{INA} + Non-inverting Input (op amp A)	
7	8	V_{DD}	Positive Power Supply
_	5	V _{INB} + Non-inverting Input (op amp B)	
_	6	V _{INB} -	Inverting Input (op amp B)
_	7	V _{OUTB}	Analog Output (op amp B)
4	4	V _{SS} Negative Power Supply	
1, 5, 8	_	NC	No Internal Connection

3.1 Analog Outputs

The output pins are low-impedance voltage sources.

3.2 Analog Inputs

The non-inverting and inverting inputs are high-impedance CMOS inputs with low bias and leakage currents.

3.3 Power Supply Pins

The positive power supply pin (V_{DD}) is 1.8V to 5.5V higher than the negative power supply pin (V_{SS}). For normal operation, the other pins are at voltages between V_{SS} and V_{DD} .

Typically, these parts are used in a single (positive) supply configuration. In this case, V_{SS} is connected to ground and V_{DD} is connected to the supply. V_{DD} will need bypass capacitors.

4.0 APPLICATIONS INFORMATION

The RE46C311/2 family of op amps is manufactured using a state of the art CMOS process. These op amps are unity gain stable and suitable for a wide range of general purpose, low-power applications.

4.1 Rail-to-Rail Input

4.1.1 PHASE REVERSAL

The RE46C311/2 op amps are designed to not exhibit phase inversion when the input pins exceed the supply voltages. Figure 2-4 shows an input voltage exceeding both supplies with no phase inversion.

4.1.2 INPUT VOLTAGE AND CURRENT LIMITS

The ESD protection on the inputs can be depicted as shown in Figure 4-1. This structure was chosen to protect the input transistors and to minimize input bias current (I_B). The input ESD diodes clamp the inputs when they try to go more than one diode drop below V_{SS} or one diode drop above V_{DD} .

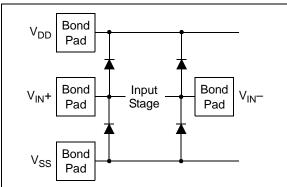


FIGURE 4-1: Simplified Analog Input ESD Structures.

In order to prevent damage and/or improper operation of these amplifiers, the circuit must limit the currents (and voltages) at the input pins (see Absolute Maximum Ratings †).

A significant amount of current can flow out of the inputs (through the ESD diodes) when the common mode voltage (V_{CM}) is below V_{SS} or above V_{DD} . Applications that are high-impedance may need to limit the usable voltage range.

4.1.3 NORMAL OPERATION

The input stage of the RE46C311/2 op amps uses two differential input stages in parallel. One operates at a low common mode input voltage (V_{CM}), while the other operates at a high V_{CM}. With this topology, the device operates with a V_{CM} up to V_{DD} and down to V_{SS}. The input offset voltage is measured at V_{CM} = V_{SS} and V_{DD} to ensure proper operation.

There are two transitions in input behavior as V_{CM} is changed. The first occurs when V_{CM} is near V_{SS} + 0.4V, and the second occurs when V_{CM} is near V_{DD} – 0.5V (see Figure 2-1 and Figure 2-2). For the best distortion performance with non-inverting gains, avoid these regions of operation.

4.2 Rail-to-Rail Output

There are two specifications that describe the output swing capability of the RE46C311/2 family of op amps. The first specification (Maximum Output Voltage Swing) defines the absolute maximum swing that can be achieved under the specified load condition. Thus, the output voltage swings to within 10 mV of either supply rail with a 50 k Ω load to V_{DD}/2. Figure 2-4 shows how the output voltage is limited when the input goes beyond the linear region of operation.

The second specification that describes the output swing capability of these amplifiers is the Linear Output Voltage Range. This specification defines the maximum output swing that can be achieved while the amplifier still operates in its linear region. To verify linear operation in this range, the large signal DC Open-Loop Gain (A_{OL}) is measured at points inside the supply rails. The measurement must meet the specified A_{OL} condition in the specification table.

4.3 Output Loads and Battery Life

The RE46C311/2 op amp family has outstanding quiescent current, which supports battery-powered applications.

Heavy resistive loads at the output can cause excessive battery drain. Driving a DC voltage of 2.5V across a 100 k Ω load resistor will cause the supply current to increase by 25 μ A, depleting the battery 43 times as fast as I $_{\Omega}$ (0.6 μ A, typical) alone.

High frequency signals (fast edge rate) across capacitive loads will also significantly increase supply current. For instance, a 0.1 μF capacitor at the output presents an AC impedance of 15.9 k Ω (1/2 πfC) to a 100 Hz sine wave. It can be shown that the average power drawn from the battery by a 5.0 $V_{p\text{-}p}$ sine wave (1.77 V_{rms}), under these conditions, is:

EQUATION 4-1:

$$\begin{split} P_{Supply} &= (V_{DD} - V_{SS}) \left(I_Q + V_{L(p-p)} f C_L \right) \\ &= (5V)(0.6 \, \mu A + 5.0 V_{p-p} \cdot 100 Hz \cdot 0.1 \mu F) \\ &= 3.0 \, \mu W + 50 \, \mu W \end{split}$$

This will drain the battery 17 times as fast as I_Q alone.

4.4 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity gain buffer (G=+1) is the most sensitive to capacitive loads, although all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., $> 60 \, \text{pF}$ when G = +1), a small series resistor at the output (R_{ISO} in Figure 4-2) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitive load.

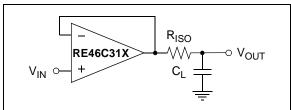


FIGURE 4-2: Output Resistor, R_{ISO}, Stabilizes Large Capacitive Loads.

Figure 4-3 gives recommended R_{ISO} values for different capacitive loads and gains. The x-axis is the normalized load capacitance (C_L/G_N), where G_N is the circuit's noise gain. For non-inverting gains, G_N and the Signal Gain are equal. For inverting gains, G_N is 1+|Signal Gain| (e.g., -1 V/V gives G_N = +2 V/V).

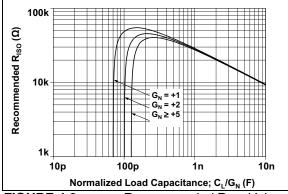


FIGURE 4-3: Recommended R_{ISO} Values for Capacitive Loads.

After selecting $R_{\rm ISO}$ for your circuit, double check the resulting frequency response peaking and step response overshoot. Modify $R_{\rm ISO}$'s value until the response is reasonable.

4.5 Supply Bypass

With this family of operational amplifiers, the power supply pin (V_{DD} for single supply) should have a local bypass capacitor (i.e., 0.01 µF to 0.1 µF) within 2 mm for good high-frequency performance. It can use a bulk capacitor (i.e., 1 µF or larger) within 100 mm to provide large, slow currents. This bulk capacitor is not required for most applications and can be shared with nearby analog parts.

4.6 Unused Op Amps

An unused op amp in a dual package (RE46C312) should be configured as shown in Figure 4-4. These circuits prevent the output from toggling and causing crosstalk. Circuit A sets the op amp at its minimum noise gain. The resistor divider produces any desired reference voltage within the output voltage range of the op amp; the op amp buffers that reference voltage. Circuit B uses the minimum number of components and operates as a comparator, but it may draw more current.

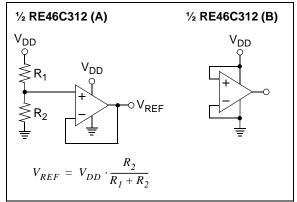


FIGURE 4-4: Unused Op Amps.

4.7 PCB Surface Leakage

In applications where low input bias current is critical, printed circuit board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow, which is greater than the RE46C311/2 family's leakage current at +25°C.

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. Figure 4-5 shows an example of this type of layout.

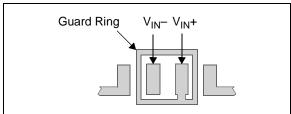


FIGURE 4-5: Example Guard Ring Layout for Inverting Gain.

- 1. Non-inverting Gain and Unity Gain Buffer:
 - a) Connect the non-inverting pin (V_{IN}+) to the input with a wire that does not touch the PCB surface.
 - b) Connect the guard ring to the inverting input pin (V_{IN}-). This biases the guard ring to the Common mode input voltage.
- Inverting Gain and Transimpedance Gain (convert current to voltage, such as photo detectors) amplifiers:
 - a) Connect the guard ring to the non-inverting input pin (V_{IN}+). This biases the guard ring to the same reference voltage as the op amp (e.g., V_{DD}/2 or ground).
 - b) Connect the inverting pin (V_{IN}-) to the input with a wire that does not touch the PCB surface.

4.8 Application Circuits

4.8.1 INSTRUMENTATION AMPLIFIER

The RE46C311/2 op amp is well suited for conditioning sensor signals in battery-powered applications. Figure 4-6 shows a two op amp instrumentation amplifier, using the RE46C312, that works well for applications requiring rejection of Common mode noise at higher gains. The reference voltage (V_{REF}) is supplied by a low impedance source. In single supply applications, V_{REF} is typically $V_{DD}/2$.

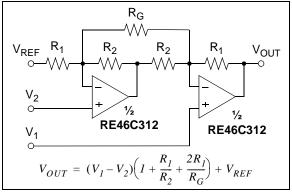


FIGURE 4-6: Two Op Amp Instrumentation Amplifier.

5.0 DESIGN AIDS

Microchip provides the basic design tools needed for the RE46C311/2 family of op amps.

5.1 Microchip Advanced Part Selector (MAPS)

MAPS is a software tool that helps semiconductor professionals efficiently identify Microchip devices that fit a particular design requirement. Available at no cost from the Microchip website at www.microchip.com/ maps, the MAPS is an overall selection tool for Microchip's product portfolio that includes Analog, Memory, MCUs and DSCs.

Using this tool you can define a filter to sort features for a parametric search of devices and export side-by-side technical comparison reports. Helpful links are also provided for data sheets, purchase, and sampling of Microchip parts.

5.2 Analog Demonstration and Evaluation Boards

Microchip offers a broad spectrum of Analog Demonstration and Evaluation Boards that are designed to help you achieve faster time to market. For a complete listing of these boards and their corresponding user's guides and technical information, visit the Microchip web site at www.microchip.com/analogtools.

Three of our boards that are especially useful are:

- P/N SOIC8EV: 8-Pin SOIC/MSOP/TSSOP/DIP Evaluation Board
- P/N SOIC14EV: 14-Pin SOIC/TSSOP/DIP Evaluation Board
- P/N MCP651EV-VOS: MCP651 Input Offset Evaluation Board

5.3 Application Notes

The following Microchip Application Notes are available on the Microchip web site at www.microchip.com/appnotes and are recommended as supplemental reference resources.

ADN003: "Select the Right Operational Amplifier for your Filtering Circuits", DS21821

AN722: "Operational Amplifier Topologies and DC Specifications", DS00722

AN723: "Operational Amplifier AC Specifications and Applications", DS00723

AN884: "Driving Capacitive Loads With Op Amps", DS00884

AN990: "Analog Sensor Conditioning Circuits – An Overview". DS00990

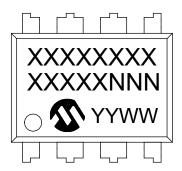
These application notes and others are listed in the design guide:

"Signal Chain Design Guide", DS21825

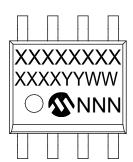
6.0 PACKAGING INFORMATION

6.1 Package Marking Information

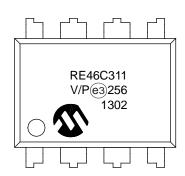
8-Lead PDIP (300 mil)



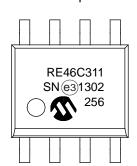
8-Lead SOIC (3.90 mm)



Example



Example



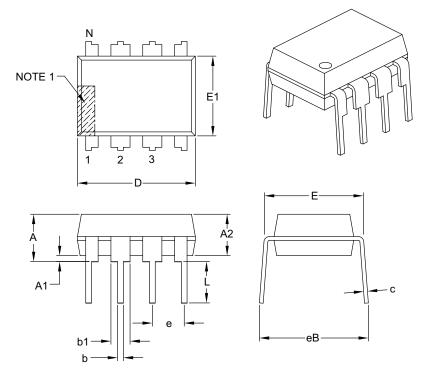
Legend: XX...X Customer-specific information
Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

alphanumeric traceability code
Pb-free JEDEC designator for Matte Tin (Sn)
This package is Pb-free. The Pb-free JEDEC designator ((e3))
can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES		
Dimension Limi		MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		.100 BSC		
Top to Seating Plane	A	_	_	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	_	-	
Shoulder to Shoulder Width	E	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eB	_	_	.430	

Notes:

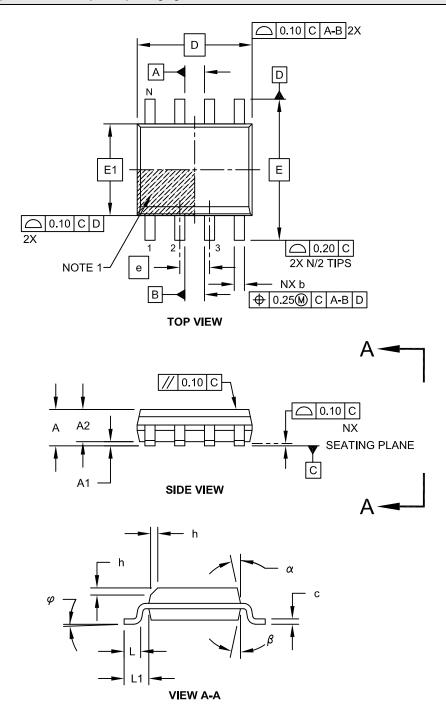
- 1. Pin 1 visual index feature may vary, but must be located with the hatched area.
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

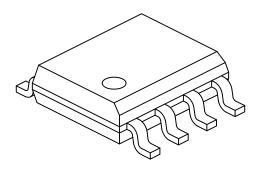
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057C Sheet 1 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	N	/ILLIMETER	S		
Dimensio	Dimension Limits		NOM	MAX	
Number of Pins	N		8		
Pitch	е		1.27 BSC		
Overall Height	Α	-	-	1.75	
Molded Package Thickness	A2	1.25	-	ı	
Standoff §	A1	0.10	-	0.25	
Overall Width	Е	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D	4.90 BSC			
Chamfer (Optional)	h	0.25	-	0.50	
Foot Length	L	0.40	-	1.27	
Footprint	L1		1.04 REF		
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.17	-	0.25	
Lead Width	b	0.31	-	0.51	
Mold Draft Angle Top	α	5°	-	15°	
Mold Draft Angle Bottom	β	5°	-	15°	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

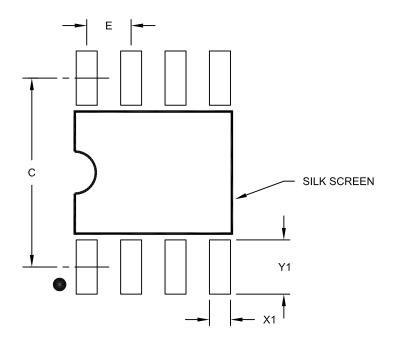
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	N	IILLIMETER	S
Dimension	Dimension Limits		NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

APPENDIX A: REVISION HISTORY

Revision A (May 2013)

• Original Release of this Document.

RE46C311/2

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	X X X	Exa	amples:	
 Device	Package Number Lead Free/	a)	RE46C311E8F:	8LD PDIP package, RoHS Compliant
	of Pins Tape and Reel	b)	RE46C311S8F:	8LD SOIC package, RoHS Compliant
Device:	RE46C311: Single Low-Input Leakage Op Amp RE46C312: Dual Low-Input Leakage Op Amp	c)	RE46C311S8TF:	8LD SOIC package, Tape and Reel
Package:	E = Plastic Dual In-Line (300 mil Body), 8-lead (PDIP)	a)	RE46C312E8F:	8LD PDIP package, RoHS Compliant
l donago.	S = Small Plastic Outline - Narrow, 3.90 mm Body, 8-Lead (SOIC)	b)	RE46C312S8F:	8LD SOIC package, RoHS Compliant
	` ,	c)	RE46C312S8TF:	8LD SOIC package, Tape and Reel

RE46C311/2

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

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